

12N10P

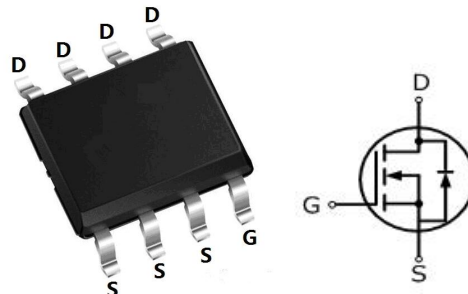
12 Amps, 100 Volts N-CHANNEL Power MOSFET

FEATURE

- 12A, 100V, $R_{DS(ON)MAX}=36m\Omega$ $V_{GS}=10V/10A$
- Low gate charge
- Low C_{iss}
- Fast switching
- 100% avalanche tested
- Improved dv/dt capability

APPLICATION

- High Frequency Piont-of-Load Synchronous Buck Converter for MB/NB/UMPC/VGA
- Networking DC-DC Power System
- LCD/LED back light



SOP8L PIN CONFIGURATION

GENERAL DESCRIPTION

The 12N10P is the highest performance trench N-ch MOSFETs with extreme high cell density, which provide excellent RDSON and gate charge for most of the synchronous buck converter applications.

The 12N10P meet the RoHS and Green product requirement, 100% EAS guaranteed with full function reliability approved.

Absolute Maximum Ratings ($T_C=25^\circ C$, unless otherwise noted)

Parameter	Symbol	12N10P	UNIT
Drain-Source Voltage	V_{DSS}	100	V
Gate-Source Voltage	V_{GSS}	± 20	
Continuous Drain Current	I_D	12	A
Pulsed Drain Current (Note 1)	I_{DM}	48	
Single Pulse Avalanche Energy (Note 2)	E_{AS}	36	mJ
Avalanche Current	I_{AS}	12	A
Reverse Diode dv/dt (Note 3)	dv/dt	5.5	V/ns
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 to +150	$^\circ C$
Channel Temperature	T_{CH}	150	$^\circ C$
Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds	T_L	260	$^\circ C$

Thermal Characteristics

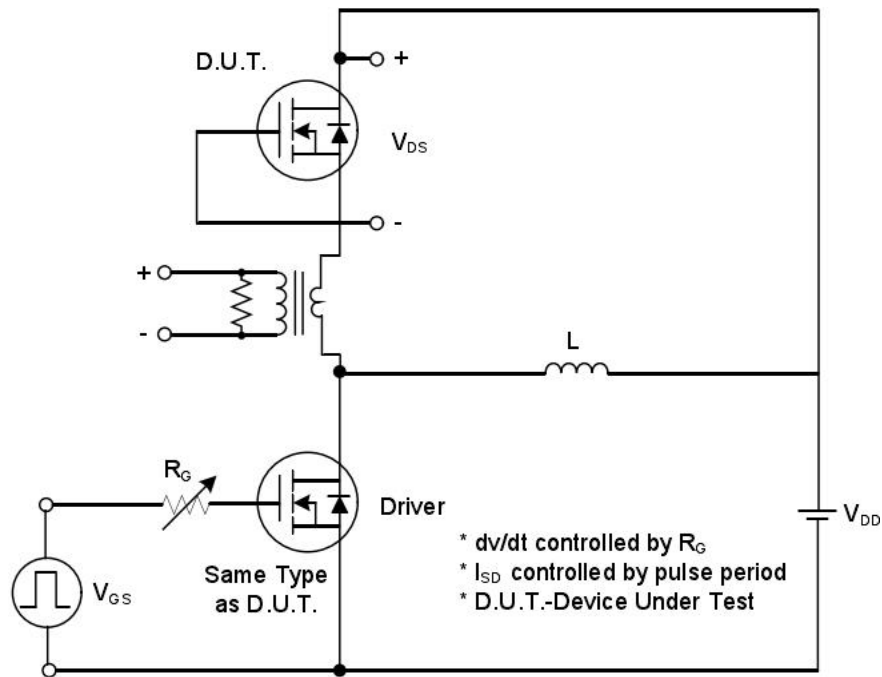
Parameter	Symbol	MAX	Units
Thermal resistance, Channel to Case	$R_{th(ch-c)}$	18	$^\circ C/W$
Thermal resistance, Channel to Ambient	$R_{th(ch-a)}$	72	$^\circ C/W$
Maximum Power Dissipation	$T_C=25^\circ C$ P_D	3.6	W

Electrical Characteristics (T _c =25℃ ,unless otherwise noted)						
Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V,I _D =250uA	100	—	—	V
Breakdown Temperature Coefficient	ΔBV _{DSS} /ΔT _J	Reference to 25℃ , I _D =250uA	—	0.06	—	V/℃
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =100V _{GS} =0V	—	—	1	μ A
	I _{DSS}	V _{DS} =100V _{GS} =0V (T _J =55℃)	—	—	5	μ A
Gate-Body Leakage Current,Forward	I _{GSS}	V _{GS} =± 20V _{DS} =0V	—	—	± 100	nA
On Characteristics						
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =10V,I _D =250uA	1.0	—	3.0	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V,I _D =10A	—	32	36	m Ω
Dynamic Characteristics						
Input Capacitance	C _{iss}	V _{DS} =50V,V _{GS} =0V, f=1.0MHZ	—	2020	—	pF
Output Capacitance	C _{oss}		—	450	—	pF
Reverse Transfer Capacitance	C _{rss}		—	260	—	pF
Switching Characteristics						
Turn-On Delay Time	t _{d(on)}	V _{DD} =50V,I _D =1A, R _G =6.8Ω,V _{GS} =10V R _L =25Ω, (Note4,5)	—	25	—	ns
Turn-On Rise Time	t _r		—	18.5	—	ns
Turn-Off Delay Time	t _{d(off)}		—	58	—	ns
Turn-Off Fall Time	t _f		—	75	—	ns
Total Gate Charge	Q _g	V _{DS} =50V,I _D =6A, V _{GS} =10V, (Note4,5)	—	50	—	nC
Gate-Source Charge	Q _{gs}		—	13	—	nC
Gate-Drain Charge	Q _{gd}		—	11	—	nC
Drain-Source Body Diode Charcteristics and Maximum Ratings						
Continuous Diode Forward Current	I _S	V _G = V _D = 0V, Force Current	—	—	12	A
Pulsed Diode Forward Current	I _{SM}		—	—	48	A
Diode Forward Voltage	V _{SD}	I _S =12A,V _{GS} =0V	—	—	1.3	V

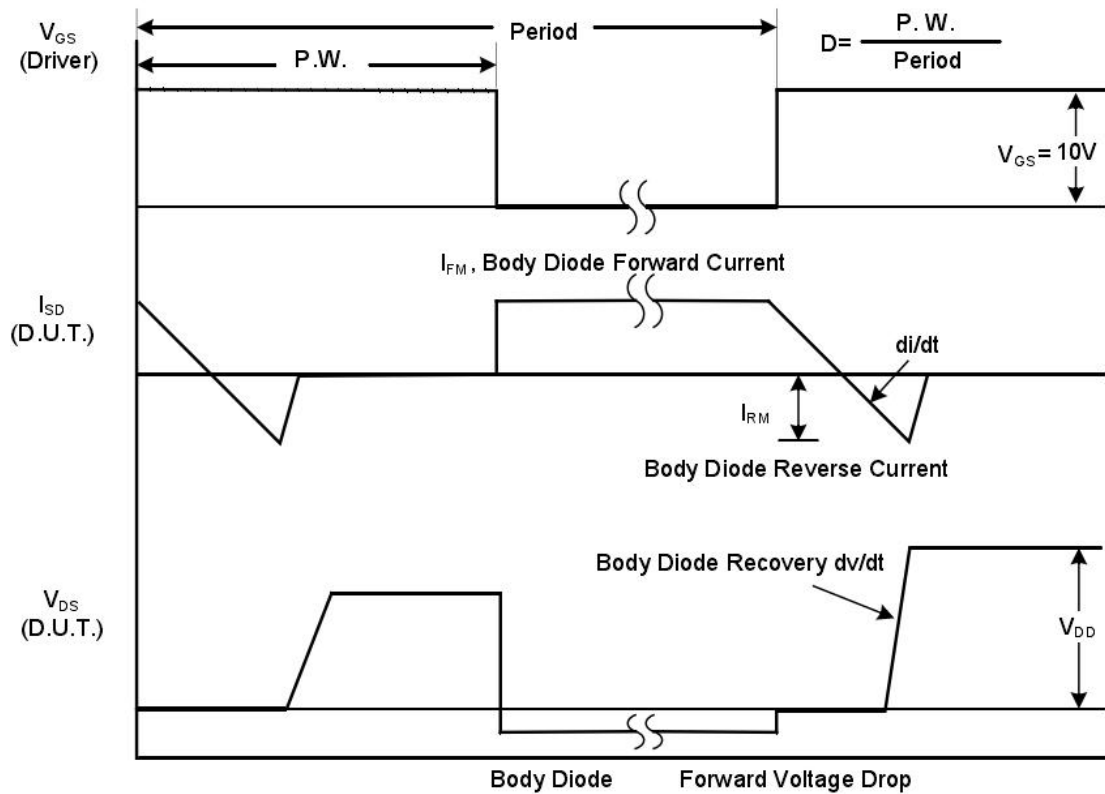
Notes

1. Repetitive Rating: pulse width limited by maximum junction temperature.
2. V_{DD}=25V, L=0.5mH, R_G=25Ω, I_{AS}=12A, starting T_J=25°C.
3. I_{SD}≤I_D, dI/dt=200A/μs, V_{DD}≤BV_{DSS}, starting T_J=25°C, Pulse width≤300μs; duty cycle≤2%.
4. Repetitive rating; pulse width limited by maximum junction temperature.

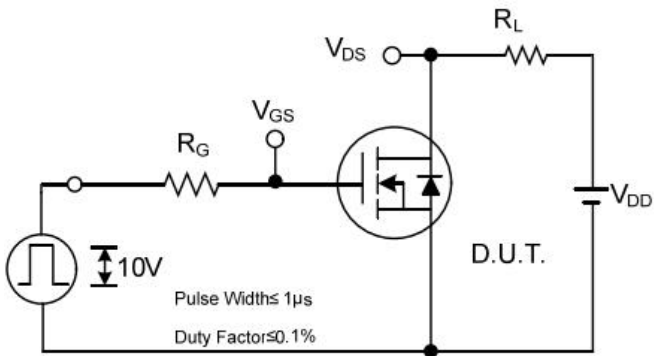
RATING AND CHARACTERISTIC CURVES



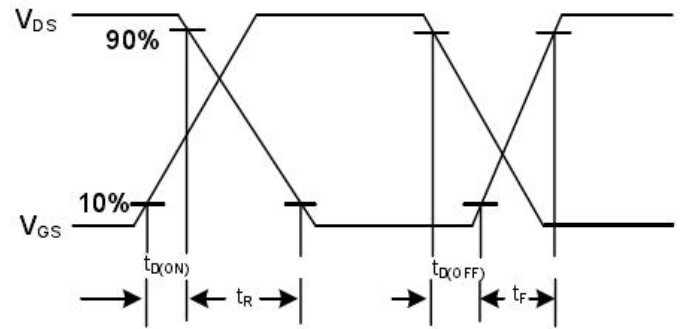
Peak Diode Recovery dv/dt Test Circuit



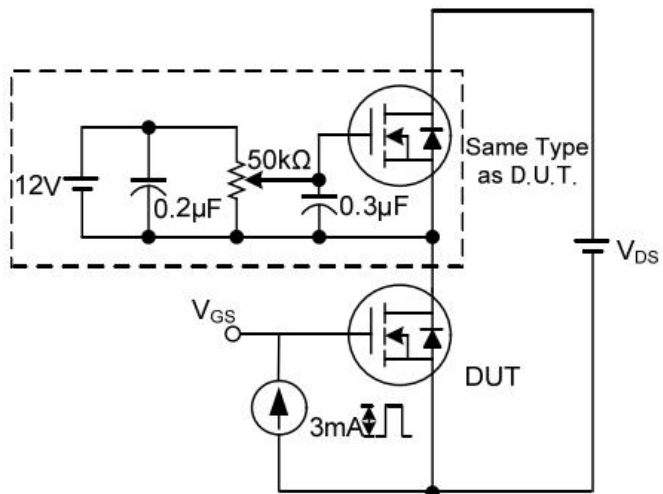
Peak Diode Recovery dv/dt Waveforms



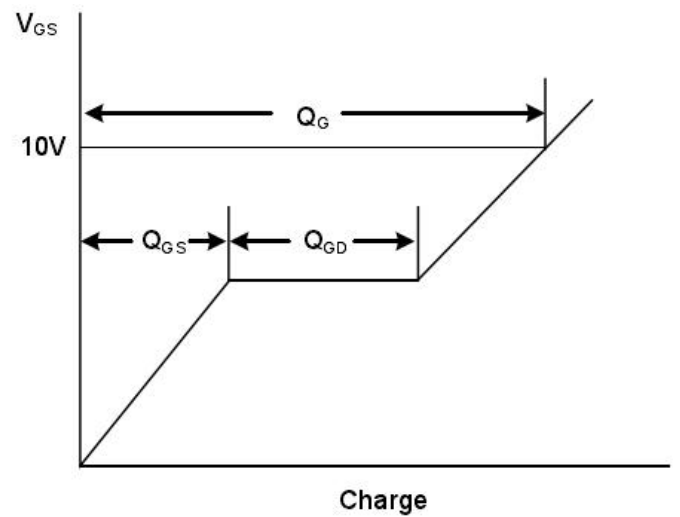
Switching Test Circuit



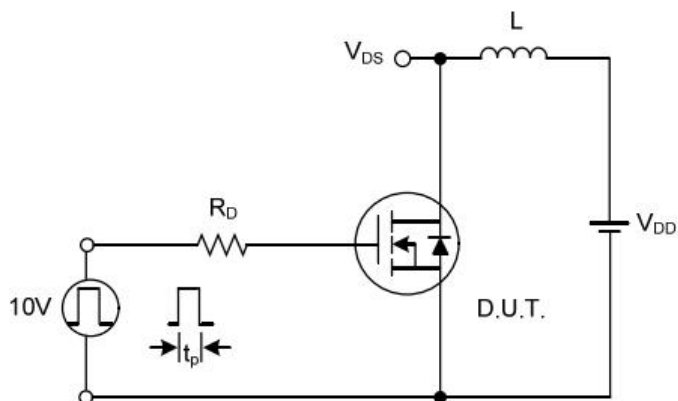
Switching Waveforms



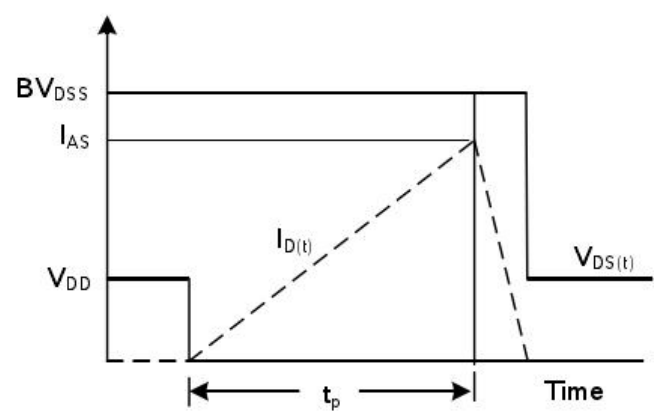
Gate Charge Test Circuit



Gate Charge Waveform

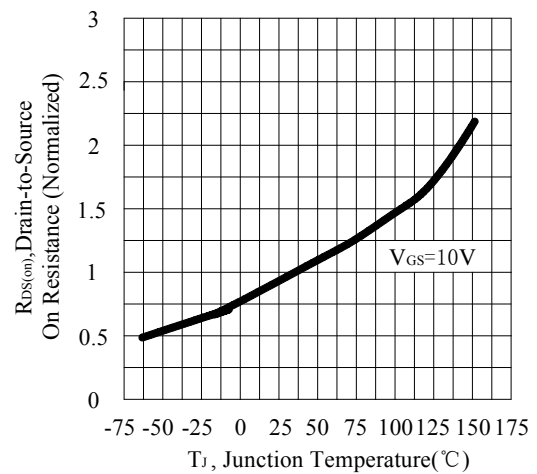
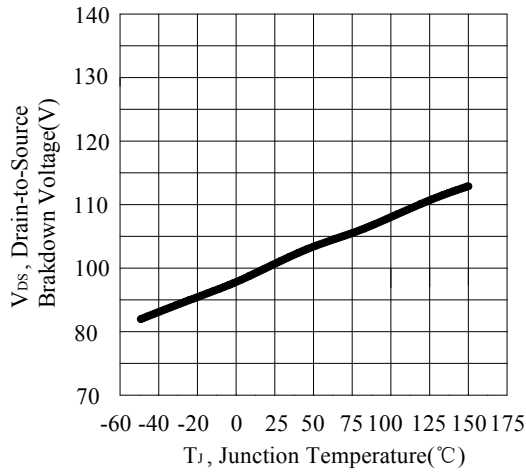
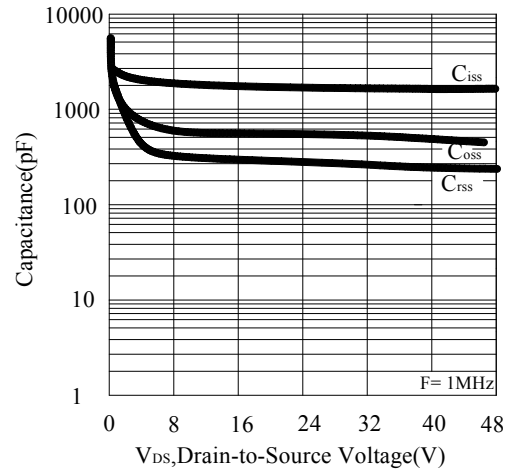
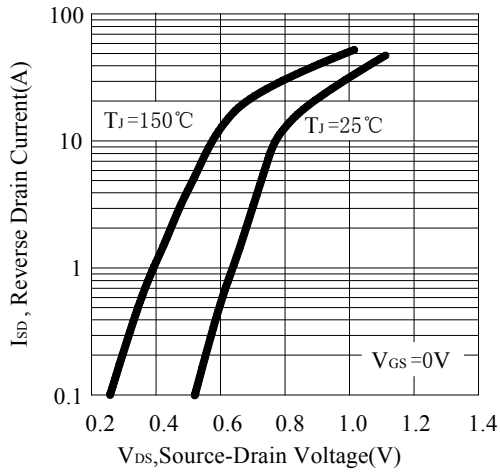
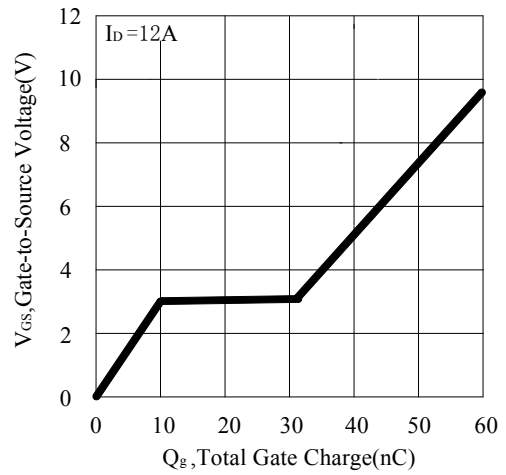
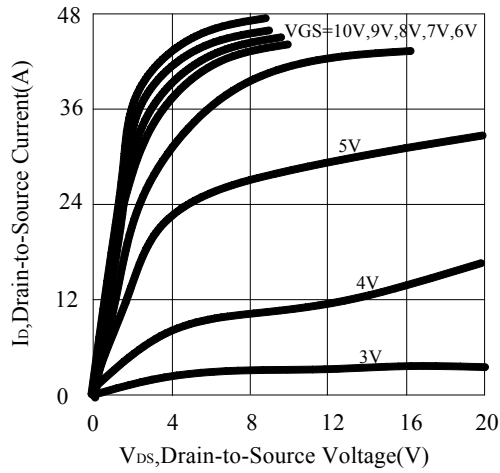


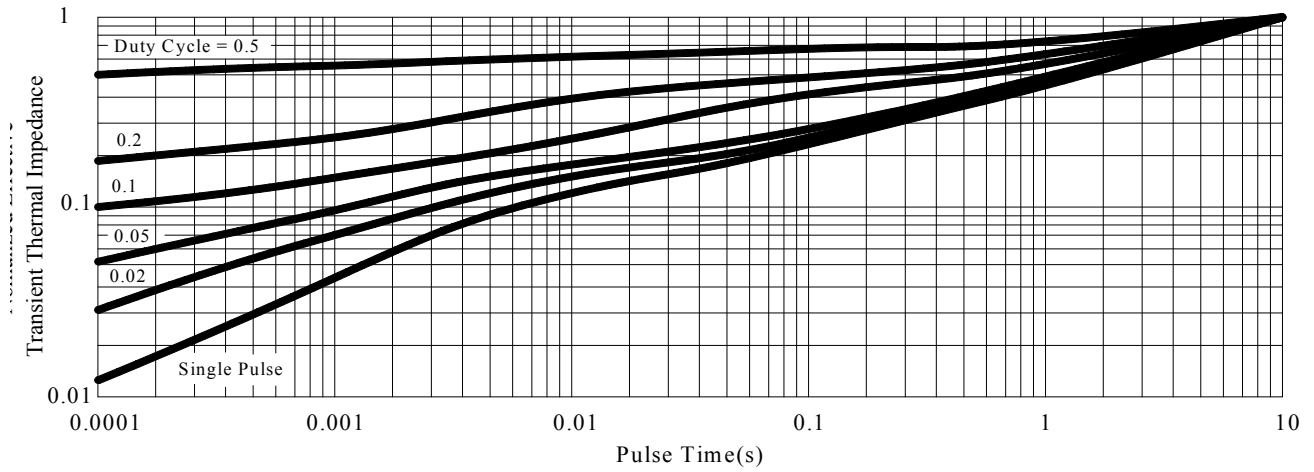
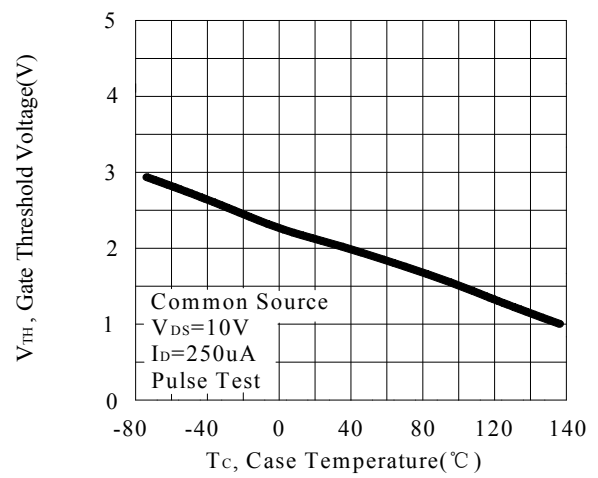
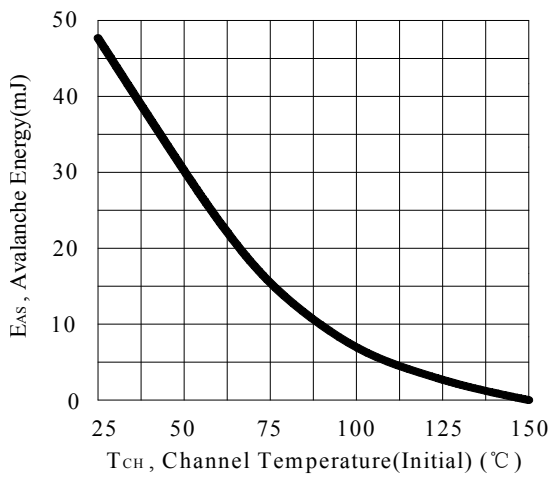
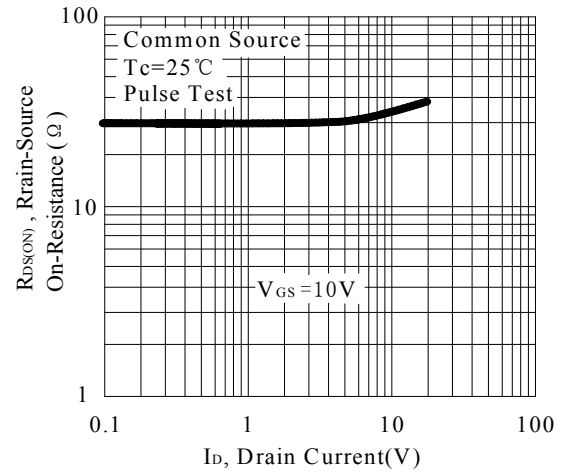
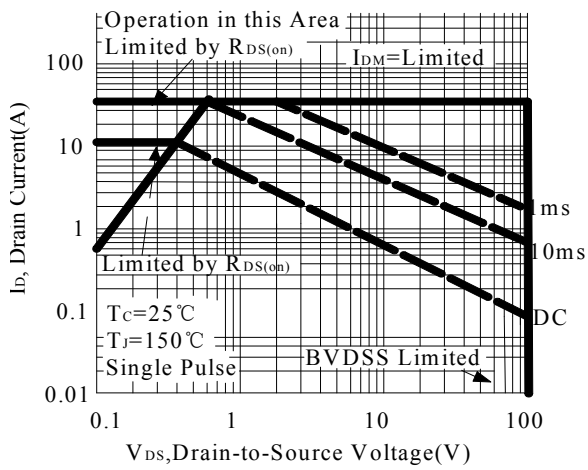
Unclamped Inductive Switching Test Circuit



Unclamped Inductive Switching Waveforms

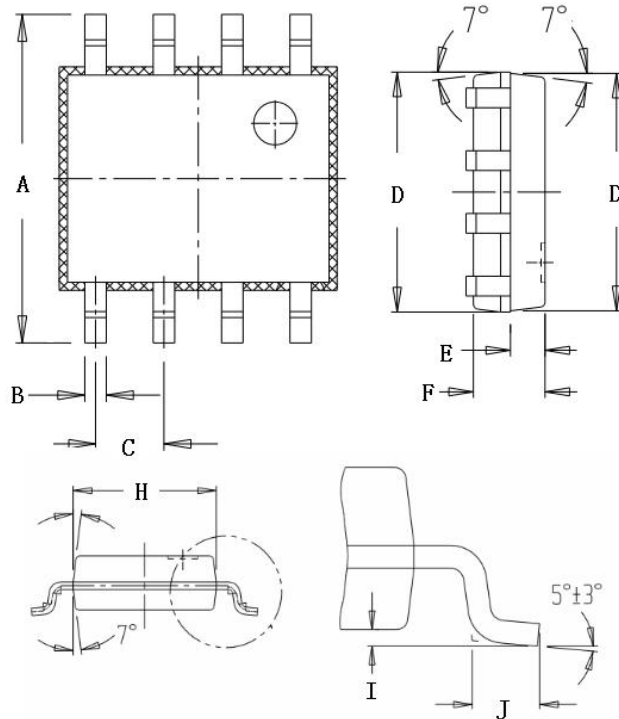
RATING AND CHARACTERISTIC CURVES





PACKAGE OUTLINE DIMENSIONS

SOP8L



SOP8L		
Dim	Min	Max
A	.236 (6.0)	.245 (6.20)
B	.014 (0.37)	.017 (0.43)
C	—	.050 (1.27)
D	.188 (4.80)	.194 (4.92)
E	.025 (0.65)	.030 (0.75)
F	.055 (1.40)	.060 (1.50)
H	.149 (3.80)	.154 (3.90)
I	.003 (0.10)	.008 (0.20)
J	.019 (0.50)	.028 (0.70)

Dimensions in inches and (millimeters)